

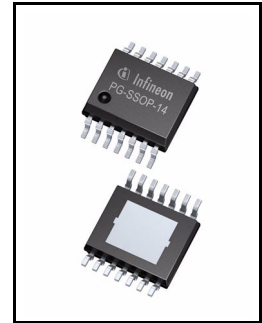
# TLS835B2ELVSE

## Low Dropout Linear Voltage Regulator



### Features

- Wide input voltage range from 3.0 V to 40 V
- Selectable output voltage 5 V or 3.3 V
- Output voltage precision  $\leq \pm 2\%$
- Output current capability up to 350 mA
- Ultra low current consumption, typical 20  $\mu\text{A}$
- Very low dropout voltage, typical 100 mV at 100 mA
- Stable with ceramic output capacitor of 1  $\mu\text{F}$
- Enable
- Overtemperature shutdown
- Output current limitation
- Wide temperature range
- Green Product (RoHS compliant)



### Potential applications

- Automotive or other supply systems that are connected to the battery permanently
- Automotive supply systems that need to operate in cranking condition

### Product validation

Qualified for Automotive Applications. Product Validation according to AEC-Q100/101

### Description

The TLS835B2 is a linear voltage regulator with high performance, very low dropout linear voltage and very low quiescent current.

With an input voltage range of 3 V to 40 V and very low quiescent current of only 20  $\mu\text{A}$ , this regulator is perfectly suitable for automotive or other supply systems permanently connected to the battery.

The new loop concept combines fast regulation and very high stability while requiring only one small ceramic capacitor of 1  $\mu\text{F}$  at the output. At output currents below 100 mA the device will have a very low dropout voltage of only 100 mV (for 5 V output voltage) and 120 mV (for 3.3 V output voltage). The operating range starts at an input voltage of only 3 V (extended operating range). This makes the TLS835B2 suitable for automotive systems that need to operate during cranking condition.

The device can be switched on and off by the Enable feature.

# TLS835B2ELVSE

## Low Dropout Linear Voltage Regulator

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The output voltage of TLS835B2ELVSE can be selected between 5 V and 3.3 V by connecting the SEL pin to  $V_O$  or GND. When the SEL pin is connected to  $V_O$ , the regulator's output is set to 5 V; when the SEL pin is connected to GND, the regulator's output is set to 3.3 V.

Internal protection features like output current limitation and overtemperature shutdown protect the device from immediate damage due to failures such as output shorted to GND, overcurrent and overtemperature.

### External components

An input capacitor  $C_I$  is recommended to compensate line influences. The output capacitor  $C_O$  is necessary for the stability of the regulating circuit. TLS835B2ELVSE is designed to be stable with low ESR ceramic capacitors.

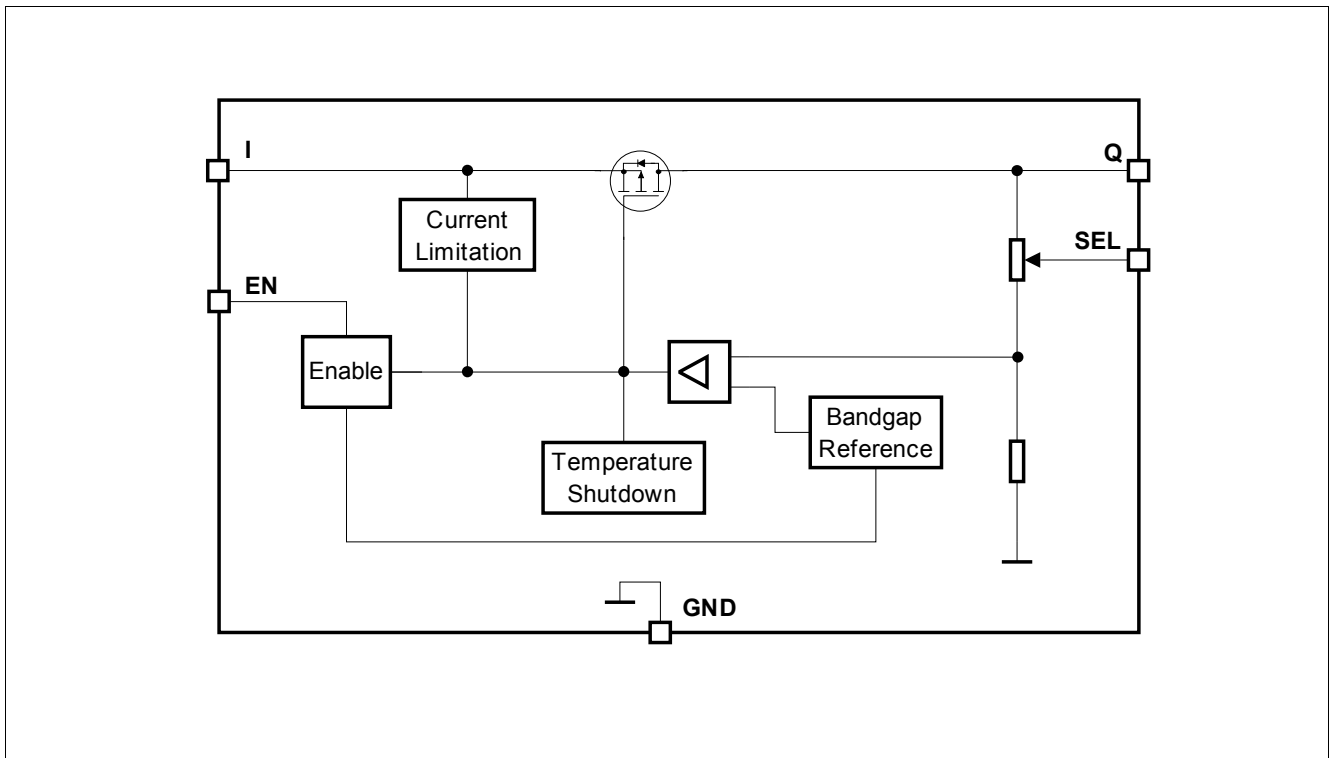
Type	Package	Marking
TLS835B2ELVSE	PG-SSOP-14	835B2VSE

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**Block diagram**

**1 Block diagram**

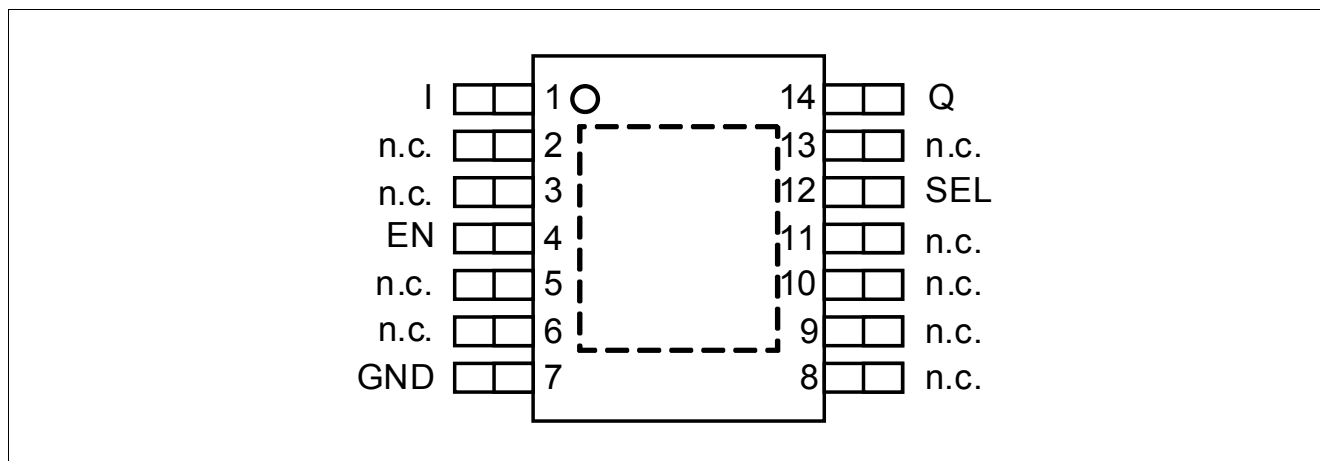


**Figure 1** Block diagram TLS835B2

**Pin configuration**

## 2 Pin configuration

### 2.1 Pin assignment TLS835B2ELVSE



**Figure 2 Pin configuration TLS835B2ELVSE**

### 2.2 Pin definitions and functions TLS835B2ELVSE

Pin	Symbol	Function
1	I	<b>Input</b> It is recommended to place a small ceramic capacitor to GND, close to the pins, in order to compensate line influences.
2	n. c.	<b>Not connected</b> Leave open or connect to GND
3	n. c.	<b>Not connected</b> Leave open or connect to GND
4	EN	<b>Enable</b> (integrated pull-down resistor) Enable the IC with high level input signal; Disable the IC with low level input signal.
5	n. c.	<b>Not connected</b> Leave open or connect to GND
6	n. c.	<b>Not connected</b> Leave open or connect to GND
7	GND	<b>Ground</b>
8	n. c.	<b>Not Connected</b> Leave open or connect to GND
9	n. c.	<b>Not connected</b> Leave open or connect to GND
10	n. c.	<b>Not connected</b> Leave open or connect to GND
11	n. c.	<b>Not connected</b> Leave open or connect to GND

**Pin configuration**

<b>Pin</b>	<b>Symbol</b>	<b>Function</b>
12	SEL	<b>Output voltage selection</b> Connect to Q to select 5 V output voltage; Connect to GND to select 3.3 V output voltage.
13	n. c.	<b>Not connected</b> Leave open or connect to GND
14	Q	<b>Output voltage</b> Connect output capacitor $C_Q$ to GND close to the pin, respecting the values specified for its capacitance and ESR in <b>“Functional range” on Page 8.</b>
Pad	–	<b>Exposed pad</b> Connect to heatsink area; Connect to GND

General product characteristics

### 3 General product characteristics

#### 3.1 Absolute maximum ratings

**Table 1 Absolute maximum ratings<sup>1)</sup>**

$T_j = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ; all voltages with respect to ground (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Typ.	Max.			
<b>Input I, Enable EN</b>							
Voltage	$V_I, V_{EN}$	-0.3	-	45	V	-	P_4.1.1
<b>Output Q</b>							
Voltage	$V_Q$	-0.3	-	7	V	-	P_4.1.2
<b>Select SEL</b>							
voltage	$V_{SEL}$	-0.3	-	7	V	-	P_4.1.3
<b>Temperatures</b>							
Junction temperature	$T_j$	-40	-	150	$^\circ\text{C}$	-	P_4.1.5
Storage temperature	$T_{stg}$	-55	-	150	$^\circ\text{C}$	-	P_4.1.6
<b>ESD absorption</b>							
ESD susceptibility to GND	$V_{ESD}$	-2	-	2	kV	<sup>2)</sup> HBM	P_4.1.7
ESD susceptibility to GND	$V_{ESD}$	-750	-	750	V	<sup>3)</sup> CDM at all pins	P_4.1.8

1) Not subject to production test, specified by design.

2) ESD susceptibility, HBM according to ANSI/ESDA/JEDEC JS001 (1.5 k $\Omega$ , 100 pF)

3) ESD susceptibility, Charged Device Model "CDM" according JEDEC JESD22-C101

#### Notes

1. Exceeding the absolute max ratings may cause permanent damage to the device and affects the device's reliability.
2. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

**General product characteristics**

**3.2 Functional range**

**Table 2 Functional range**

$T_j = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ; all voltages with respect to ground (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Typ.	Max.			
Input voltage range	$V_I$	$V_{Q,nom} + V_{dr}$	–	40	V	<sup>1)</sup> –	P_4.2.1
Extended input voltage range	$V_{I,ext}$	3.0	–	40	V	<sup>2)</sup> –	P_4.2.2
Enable voltage range	$V_{EN}$	0	–	40	V	–	P_4.2.3
Capacitance of output capacitor for Stability	$C_Q$	1	–	–	$\mu\text{F}$	<sup>3)4)</sup> –	P_4.2.4
Equivalent Series Resistance of output capacitor	$ESR(C_Q)$	–	–	50	$\Omega$	<sup>3)</sup> –	P_4.2.5
Junction temperature	$T_j$	-40	–	150	$^\circ\text{C}$	–	P_4.2.6

1) Output current is limited internally and depends on the input voltage, see Electrical Characteristics for more details.

2) If  $V_{I,ext,min} \leq V_I \leq V_{Q,nom} + V_{dr}$ , then  $V_Q = V_I - V_{dr}$ . If  $V_I < V_{I,ext,min}$ , then  $V_Q$  can drop to 0 V.

3) Not subject to production test, specified by design.

4) The minimum output capacitance requirement is applicable for a worst case capacitance tolerance of 30%

*Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.*



**General product characteristics**

**3.3 Thermal resistance**

Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to [www.jedec.org](http://www.jedec.org).

**Table 3 Thermal resistance TLS835B2ELVSEPG-SSOP-14 Package**

Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Typ.	Max.			
Junction to case	$R_{thJC}$	–	10	–	K/W	<sup>1)</sup> –	P_4.3.1
Junction to ambient	$R_{thJA}$	–	41	–	K/W	<sup>1)2)</sup> 2s2p board	P_4.3.2
Junction to ambient	$R_{thJA}$	–	125	–	K/W	<sup>1)3)</sup> 1s0p board, footprint only	P_4.3.3
Junction to ambient	$R_{thJA}$	–	59	–	K/W	<sup>1)3)</sup> 1s0p board, 300 mm <sup>2</sup> heatsink area on PCB	P_4.3.4
Junction to ambient	$R_{thJA}$	–	51	–	K/W	<sup>1)3)</sup> 1s0p board, 600 mm <sup>2</sup> heatsink area on PCB	P_4.3.5

- 1) Not subject to production test, specified by design
- 2) Specified  $R_{thJA}$  value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip + Package) was simulated on a 76.2 × 114.3 × 1.5 mm<sup>3</sup> board with 2 inner copper layers (2 × 70 μm Cu, 2 × 35 μm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.
- 3) Specified  $R_{thJA}$  value is according to JEDEC JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip + Package) was simulated on a 76.2 × 114.3 × 1.5 mm<sup>3</sup> board with 1 copper layer (1 × 70 μm Cu).

## **4 Block description and electrical characteristics**

### **4.1 Voltage regulation**

The output voltage  $V_Q$  is divided by a resistor network. This fractional voltage is compared to an internal voltage reference and the pass transistor is driven accordingly.

The control loop stability depends on the following factors:

- output capacitor  $C_Q$
- load current
- chip temperature
- internal circuit design

#### **Output capacitor**

To ensure stable operation, the output capacitor's capacitance and its equivalent series resistor (ESR) requirements given in **"Functional range" on Page 8** must be maintained. Because the output capacitor must buffer load steps, it should be sized according to the requirements of the application.

#### **Input capacitors, reverse polarity protection diode**

An input capacitor  $C_I$  is recommended to compensate line influences.

In order to block influences such as pulses and high frequency distortion at the input, an additional reverse polarity protection diode and a combination of several capacitors for filtering should be used. Connect the capacitors close to the component's terminals.

#### **Smooth ramp up**

In order to prevent overshoots during startup, a smooth ramp up function is implemented. This ensures almost no output voltage overshoots during startup, mostly independent from load and output capacitance.

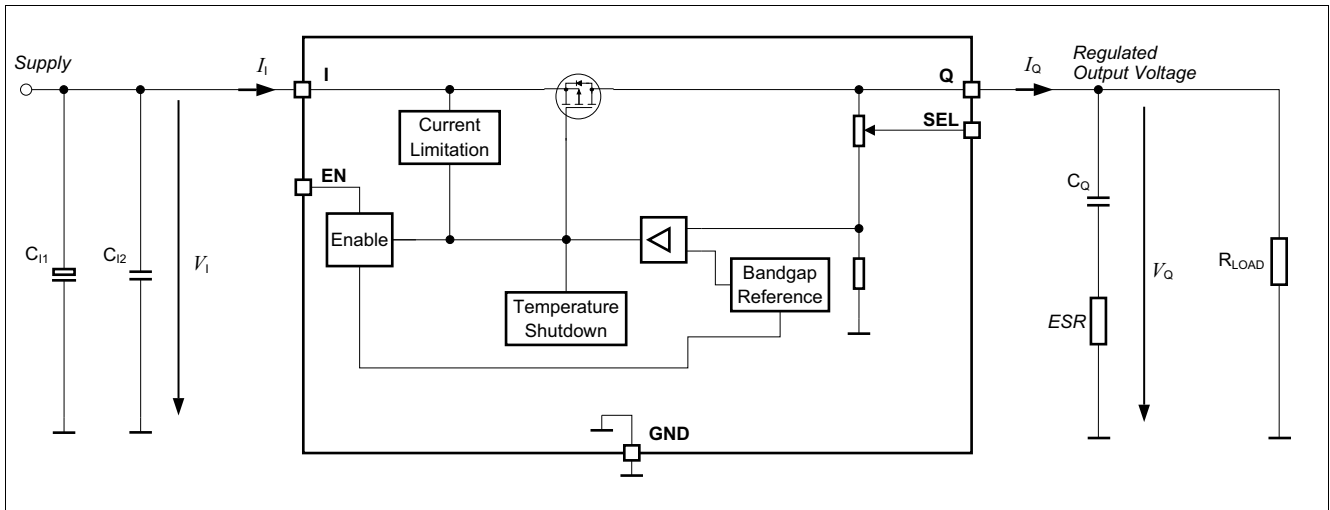
#### **Output current limitation**

If the load current exceeds the specified limit, for example due to a short circuit, then the output current is limited and the output voltage decreases.

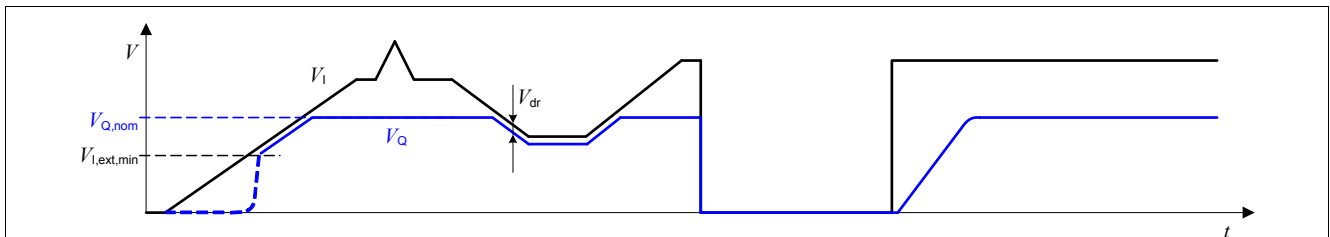
#### **Overtemperature shutdown**

The overtemperature shutdown circuit prevents the IC from immediate destruction in fault condition (for example a permanent short-circuit at the output) by switching off the power stage. After the chip has cooled down, the regulator restarts. This leads to an oscillatory behavior of the output voltage until the fault is removed. However, any junction temperature above 150°C is outside the maximum ratings and therefore significantly reduces the IC's life time.

**Block description and electrical characteristics**



**Figure 3** Voltage regulation



**Figure 4** Output voltage vs. input voltage

**Block description and electrical characteristics**

**Table 4 Electrical characteristics voltage regulator**

$T_j = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ,  $V_I = 13.5\text{ V}$ , all voltages with respect to ground (unless otherwise specified)  
 Typical values are given at  $T_j = 25^\circ\text{C}$

Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Typ.	Max.			

**5V output voltage**

Output voltage accuracy	$V_Q$	4.9	5.0	5.1	V	$0.05\text{ mA} \leq I_Q \leq 350\text{ mA}$ $5.8\text{ V} \leq V_I \leq 28\text{ V}$ SEL connected to Q	P_5.1.1
Output voltage accuracy	$V_Q$	4.9	5.0	5.1	V	$0.05\text{ mA} \leq I_Q \leq 175\text{ mA}$ $5.45\text{ V} \leq V_I \leq 40\text{ V}$ SEL connected to Q	P_5.1.2
Dropout voltage $V_{dr} = V_I - V_Q$	$V_{dr}$	–	250	500	mV	<sup>1)</sup> $I_Q = 250\text{ mA}$ , SEL connected to Q	P_5.1.7
Dropout voltage $V_{dr} = V_I - V_Q$	$V_{dr}$	–	100	200	mV	<sup>1)</sup> $I_Q = 100\text{ mA}$ , SEL connected to Q	P_5.1.9
Power Supply Ripple Rejection	$PSRR$	–	60	–	dB	<sup>2)</sup> $f_{\text{ripple}} = 100\text{ Hz}$ $V_{\text{ripple}} = 0.5 V_{pp}$ $I_Q = 10\text{ mA}$ SEL connected to Q	P_5.1.10

**3.3V output voltage**

Output voltage accuracy	$V_Q$	3.23	3.3	3.37	V	$0.05\text{ mA} \leq I_Q \leq 350\text{ mA}$ $4.21\text{ V} \leq V_I \leq 28\text{ V}$ SEL connected to GND	P_5.1.12
Output voltage accuracy	$V_Q$	3.23	3.3	3.37	V	$0.05\text{ mA} \leq I_Q \leq 175\text{ mA}$ $3.79\text{ V} \leq V_I \leq 40\text{ V}$ SEL connected to GND	P_5.1.13
Dropout voltage $V_{dr} = V_I - V_Q$	$V_{dr}$	–	300	600	mV	<sup>1)</sup> $I_Q = 250\text{ mA}$ , SEL connected to GND	P_5.1.18
Dropout voltage $V_{dr} = V_I - V_Q$	$V_{dr}$	–	120	240	mV	<sup>1)</sup> $I_Q = 100\text{ mA}$ , SEL connected to GND	P_5.1.20
Power Supply Ripple Rejection	$PSRR$	–	63	–	dB	<sup>2)</sup> $f_{\text{ripple}} = 100\text{ Hz}$ $V_{\text{ripple}} = 0.5 V_{pp}$ $I_Q = 10\text{ mA}$ SEL connected to GND	P_5.1.21

**Other electrical characteristics**

Output current limitation	$I_{Q,max}$	351	500	780	mA	$0\text{ V} < V_Q < V_{Q,nom} - 0.1\text{ V}$	P_5.1.24
Load regulation steady-state	$\Delta V_{Q,load}$	-15	-5	–	mV	$I_Q = 0.05\text{ mA}$ to $350\text{ mA}$ $V_I = 6.5\text{ V}$	P_5.1.29
Line regulation steady-state	$\Delta V_{Q,line}$	–	1	10	mV	$V_I = 8\text{ V}$ to $32\text{ V}$ $I_Q = 5\text{ mA}$	P_5.1.30

**Block description and electrical characteristics**

**Table 4 Electrical characteristics voltage regulator (cont'd)**

$T_j = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ,  $V_I = 13.5\text{ V}$ , all voltages with respect to ground (unless otherwise specified)  
 Typical values are given at  $T_j = 25^\circ\text{C}$

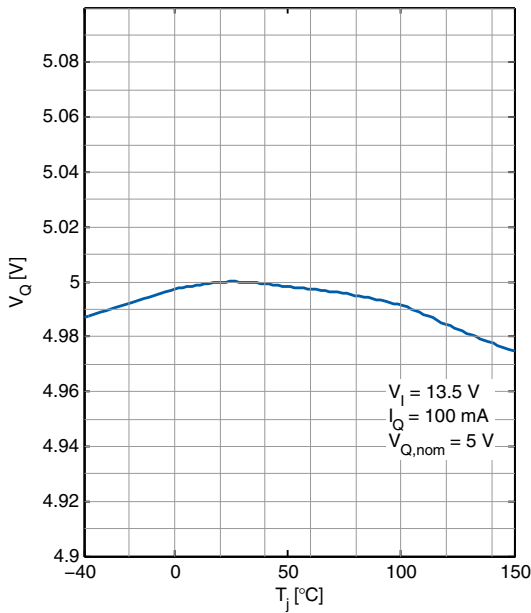
Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Typ.	Max.			
Overtemperature shutdown threshold	$T_{j,sd}$	151	175	200	$^\circ\text{C}$	<sup>2)</sup> $T_j$ increasing	P_5.1.31
Overtemperature shutdown threshold hysteresis	$T_{j,sdh}$	–	15	–	K	<sup>2)</sup> $T_j$ decreasing	P_5.1.32

1) Measured when the output voltage  $V_O$  has dropped by 100 mV while input voltage was gradually decreased.

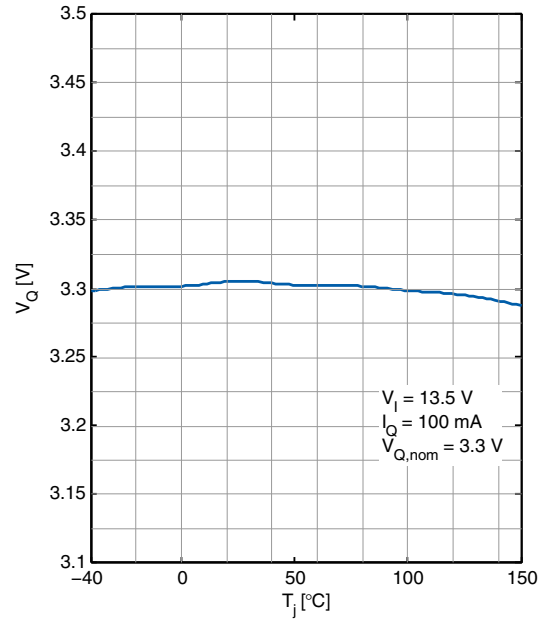
2) Not subject to production test, specified by design

### 4.2 Typical performance characteristics voltage regulator

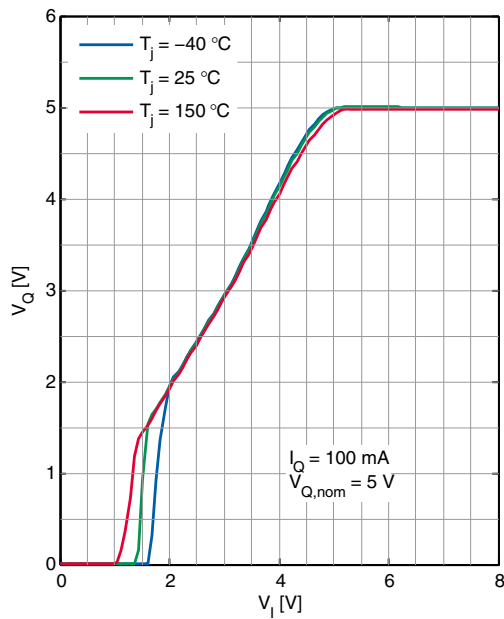
**Output voltage  $V_Q$  versus junction temperature  $T_j$**



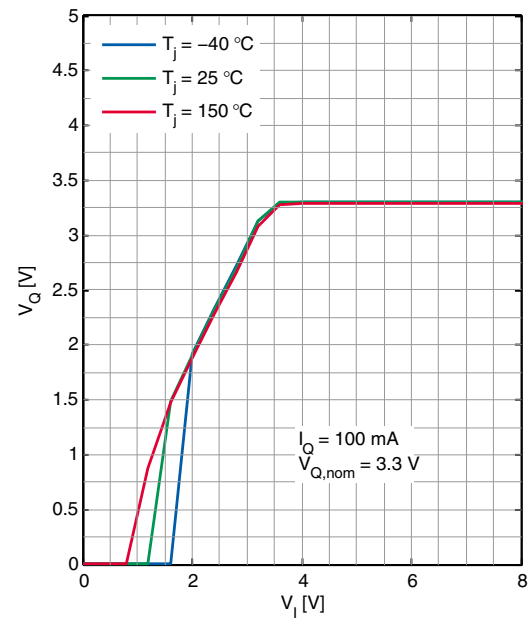
**Output voltage  $V_Q$  versus junction temperature  $T_j$**



**Output Voltage  $V_Q$  versus Input Voltage  $V_I$**

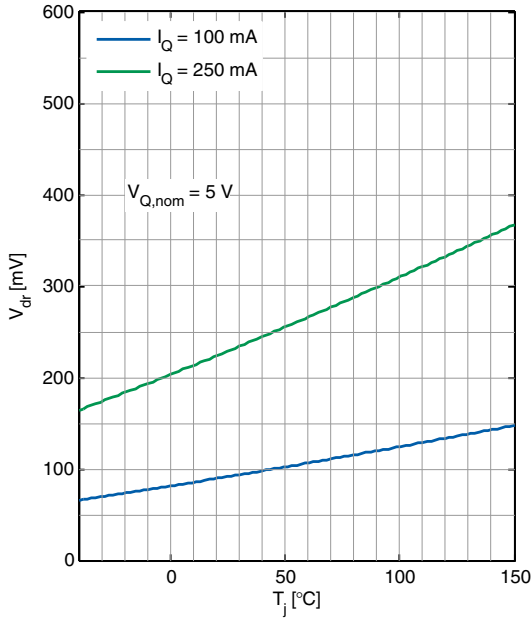


**Output Voltage  $V_Q$  versus Input Voltage  $V_I$**

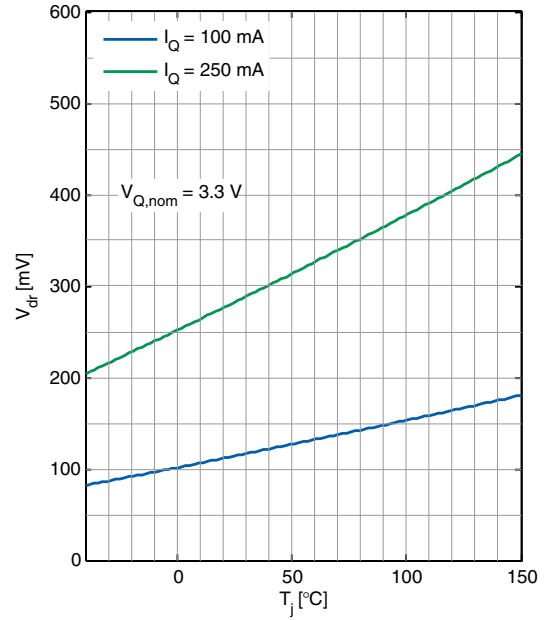


**Block description and electrical characteristics**

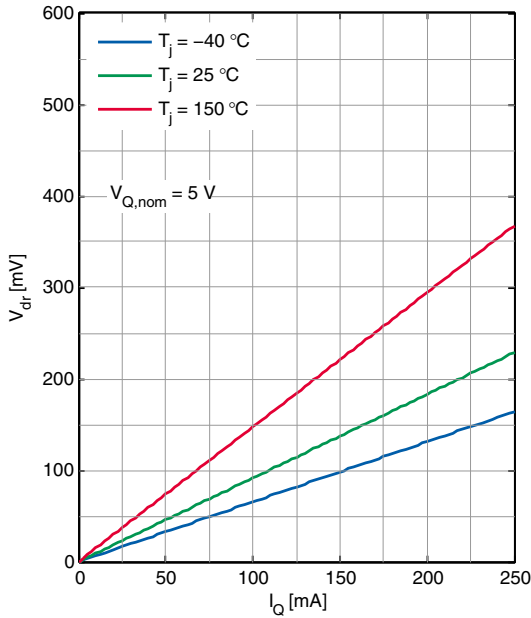
**Dropout voltage  $V_{dr}$  versus junction temperature  $T_j$**



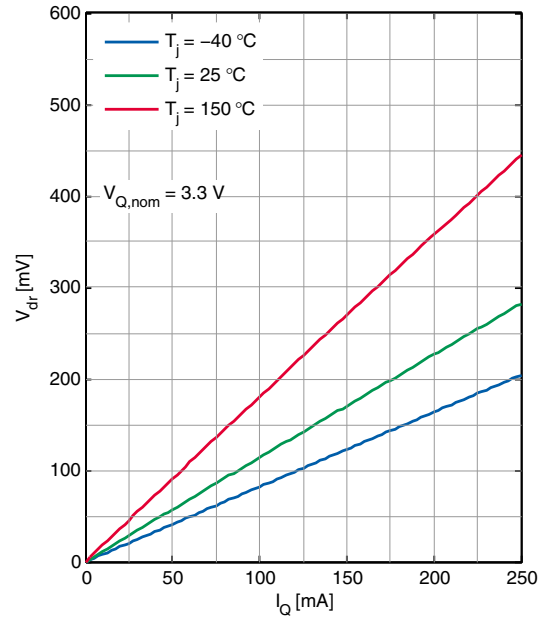
**Dropout voltage  $V_{dr}$  versus junction temperature  $T_j$**



**Dropout voltage  $V_{dr}$  versus Output Current  $I_Q$**

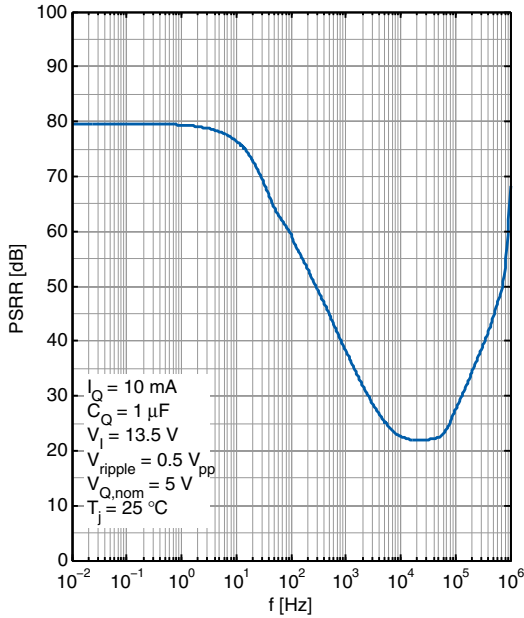


**Dropout voltage  $V_{dr}$  versus Output Current  $I_Q$**

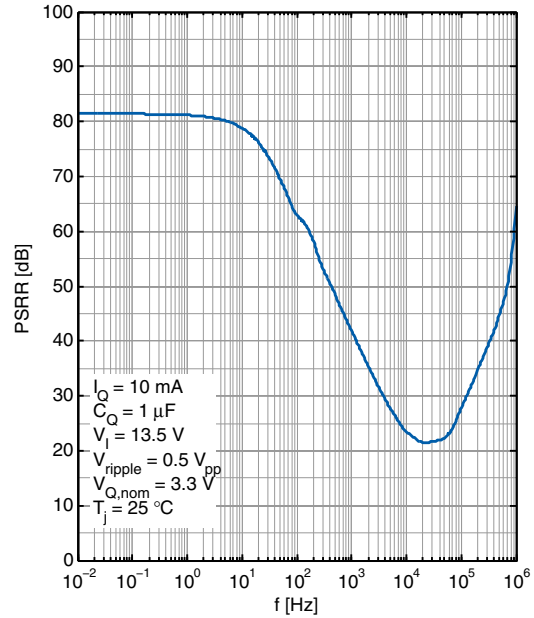


**Block description and electrical characteristics**

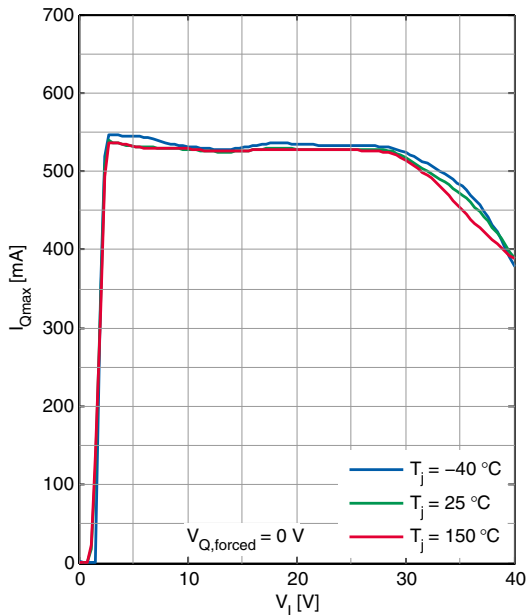
**Power Supply Ripple Rejection  $PSRR$  versus ripple frequency  $f$**



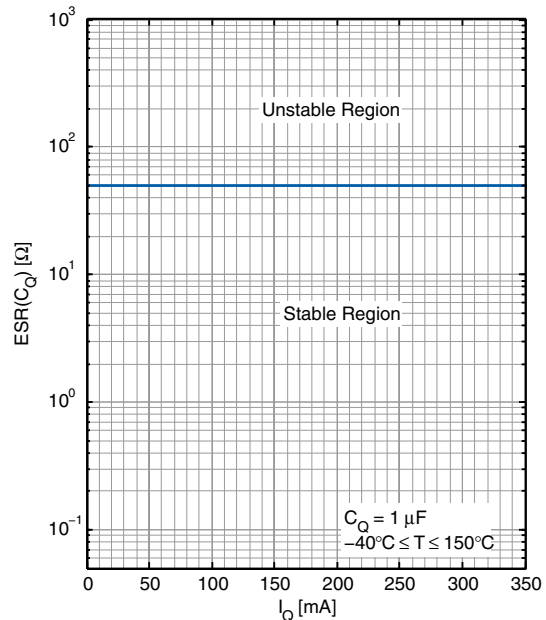
**Power Supply Ripple Rejection  $PSRR$  versus ripple frequency  $f$**



**Maximum output current  $I_Q$  versus input voltage  $V_I$**



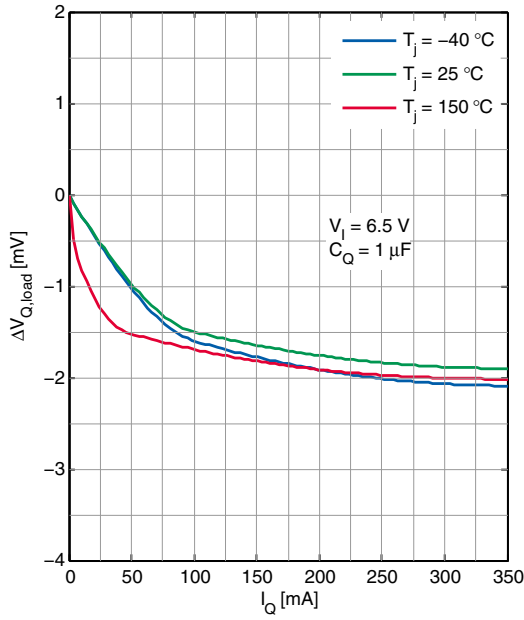
**Equivalent Series Resistance of output capacitor  $ESR(C_Q)$  versus output current  $I_Q$**



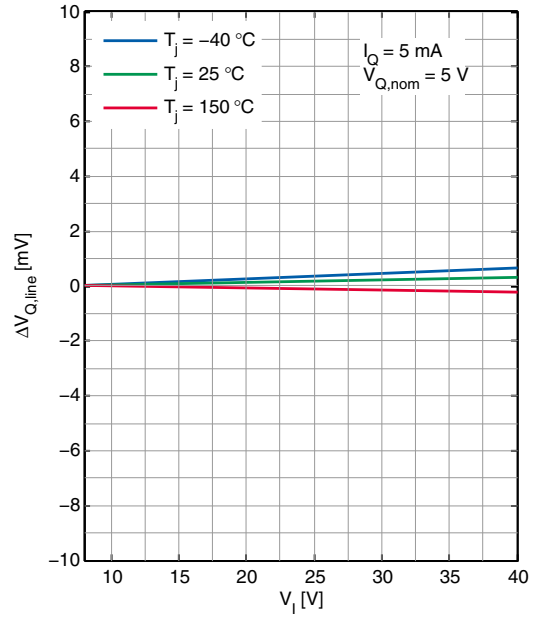


**Block description and electrical characteristics**

**Load regulation  $\Delta V_{Q,load}$  versus output current change  $I_Q$**



**Line regulation  $\Delta V_{Q,line}$  versus input voltage  $V_I$**



**Block description and electrical characteristics**

**4.3 Current consumption**

**Table 5 Electrical characteristics current consumption**

$T_j = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ,  $V_I = 13.5\text{ V}$  (unless otherwise specified)

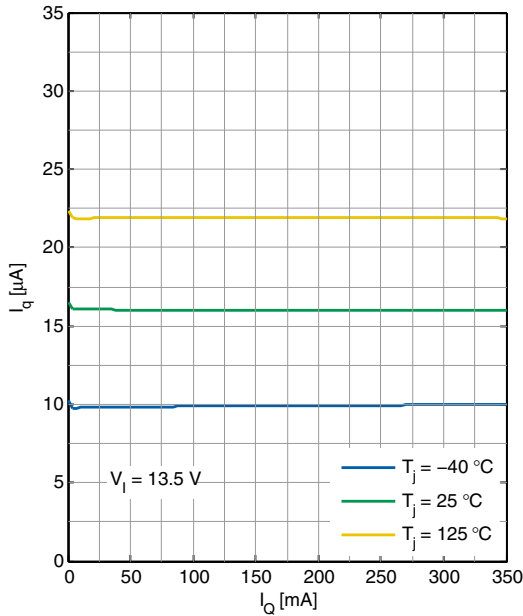
Typical values are given at  $T_j = 25^\circ\text{C}$

Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Typ.	Max.			
Current consumption $I_q = I_1$	$I_{q,off}$	–	–	1	$\mu\text{A}$	$V_{EN} = 0\text{ V}; T_j < 105^\circ\text{C}$	P_5.3.1
Current consumption $I_q = I_1$	$I_{q,off}$	–	–	2	$\mu\text{A}$	$V_{EN} = 0.4\text{ V}; T_j < 125^\circ\text{C}$	P_5.3.3
Current consumption $I_q = I_1 - I_Q$	$I_q$	–	17	25	$\mu\text{A}$	$I_Q = 0.05\text{ mA}; T_j = 25^\circ\text{C}$	P_5.3.4
Current consumption $I_q = I_1 - I_Q$	$I_q$	–	20	30	$\mu\text{A}$	$I_Q = 0.05\text{ mA}; T_j < 125^\circ\text{C}$	P_5.3.5
Current consumption $I_q = I_1 - I_Q$	$I_q$	–	22	33	$\mu\text{A}$	<sup>1)</sup> $I_Q = 350\text{ mA}; T_j < 125^\circ\text{C}$	P_5.3.6

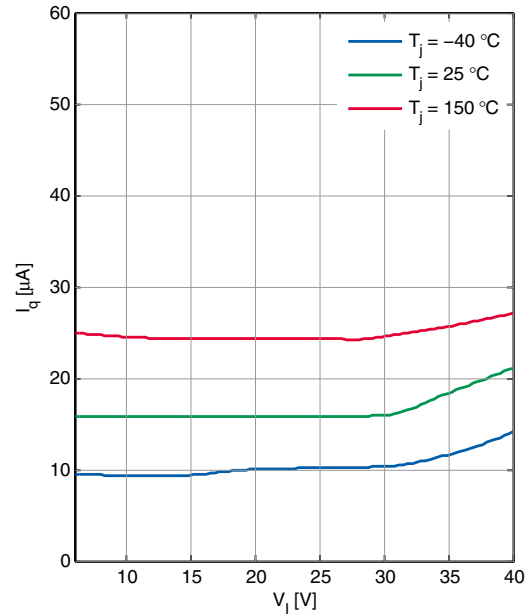
1) Not subject to production test, specified by design

#### 4.4 Typical performance characteristics current consumption

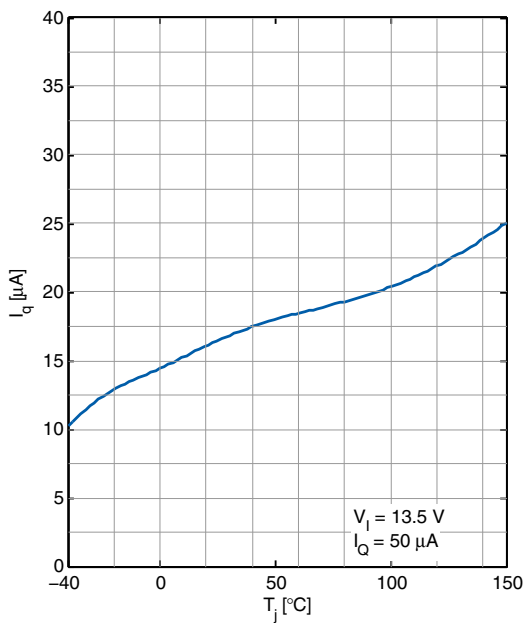
**Current consumption  $I_q$  versus output current  $I_Q$**



**Current consumption  $I_q$  versus input voltage  $V_I$**



**Current consumption  $I_q$  versus junction temperature  $T_j$**



**Block description and electrical characteristics**

**4.5 Enable**

The TLS835B2 can be switched on and off by the enable feature. Applying a “high” level as specified below ( $V_{EN} \geq 2\text{ V}$ ) to the EN pin enables the device. Applying a “low” level as specified below ( $V_{EN} \leq 0.8\text{ V}$ ) shuts down the device. The enable feature has a built in hysteresis to avoid toggling between ON/OFF state, if a signal with slow slope is applied to the EN pin.

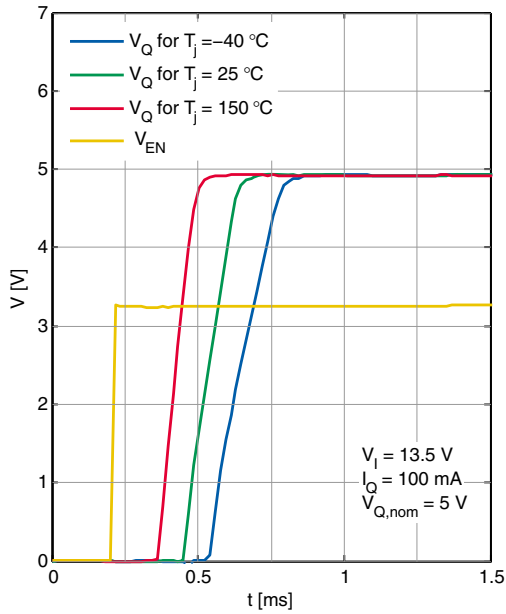
**Table 6 Electrical characteristics Enable**

$T_j = -40^\circ\text{C}$  to  $+150^\circ\text{C}$ ,  $V_I = 13.5\text{ V}$ , all voltages with respect to ground (unless otherwise specified)  
 Typical values are given at  $T_j = 25^\circ\text{C}$

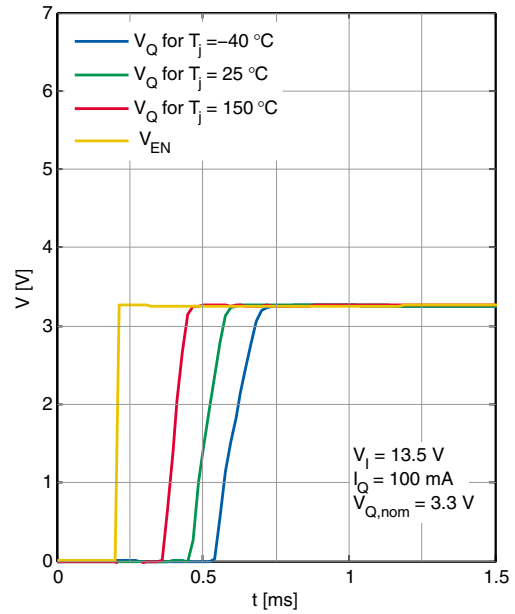
Parameter	Symbol	Values			Unit	Note or Test Condition	Number
		Min.	Typ.	Max.			
Enable “high” input voltage	$V_{EN,H}$	2	–	–	V	–	P_5.5.1
Enable “low” input voltage	$V_{EN,L}$	–	–	0.8	V	–	P_5.5.2
Enable threshold hysteresis	$V_{EN,HY}$	90	–	–	mV	–	P_5.5.3
Enable “high” input current	$I_{EN,H}$	–	–	1	$\mu\text{A}$	$V_{EN} = 5\text{ V}$	P_5.5.4
Enable “high” input current	$I_{EN,H}$	–	–	6	$\mu\text{A}$	$V_{EN} \leq 18\text{ V}$	P_5.5.5
Enable internal pull-down resistor	$R_{EN}$	2.8	10	20	$\text{M}\Omega$	–	P_5.5.6

### 4.6 Typical performance characteristics Enable

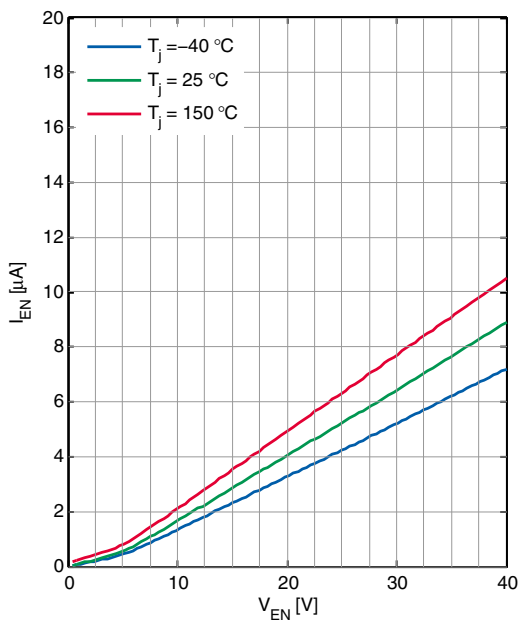
**Output voltage  $V_Q$  versus time (EN switched on)**



**Output voltage  $V_Q$  versus time (EN switched on)**



**Enable input current  $I_{EN}$  versus Enable input voltage  $V_{EN}$**



#### **4.7 Output voltage selection**

The output voltage  $V_Q$  of TLS835B2ELVSE can be selected by the SEL pin:

SEL pin connected to Q:  $V_Q = 5\text{ V}$ ;

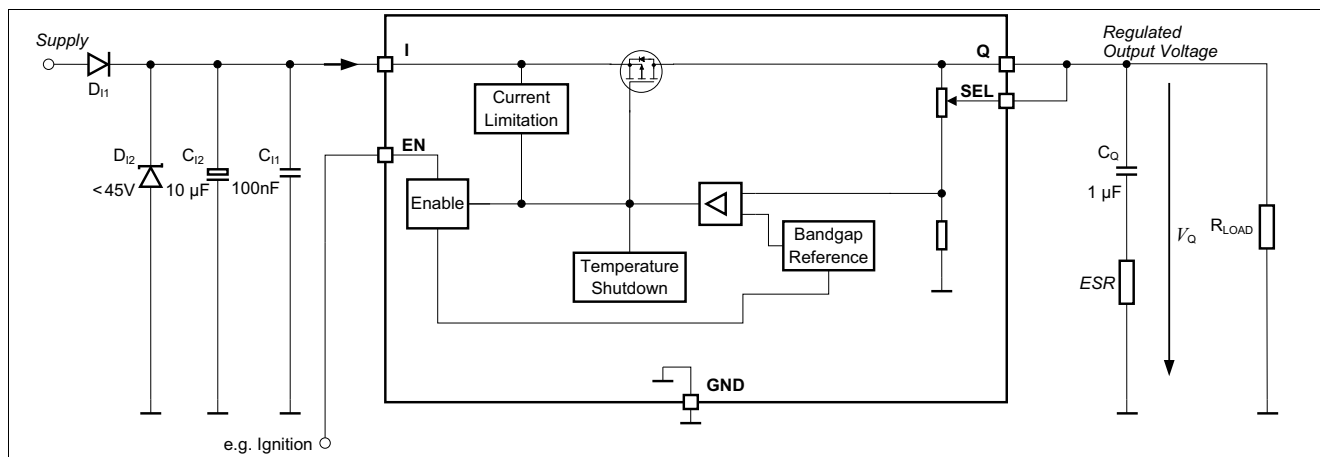
SEL pin connected to GND:  $V_Q = 3.3\text{ V}$ .

**Application information**

## 5 Application information

### 5.1 Application diagram

*Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.*



**Figure 5 Application diagram**

*Note: This is a very simplified example of an application circuit. The function must be verified in the real application.*

### 5.2 Selection of external components

#### 5.2.1 Input pin

**Figure 5** shows an exemplary input circuitry for a linear voltage regulator. A ceramic capacitor at the input, in the range of 100 nF to 470 nF, is recommended to filter out the high frequency disturbances imposed by the line, for example ISO pulses 3a/b. This capacitor must be placed very close to the input pin of the linear voltage regulator on the PCB.

An aluminum electrolytic capacitor in the range of 10 μF to 470 μF is recommended as an input buffer to smooth out high energy pulses, such as ISO pulse 2a. This capacitor must be placed close to the input pin of the linear voltage regulator.

An overvoltage suppressor diode can be used to further suppress any high voltage beyond the maximum rating of the linear voltage regulator and to protect the device from damage due to overvoltage.

The external components at the input pin are optional, but they are recommended in case of possible external disturbances.

#### 5.2.2 Output pin

An output capacitor is mandatory for the stability of linear voltage regulators. Furthermore it serves as an energy buffer during load jumps, to compensate and maintain a constant output voltage potential. It must be dimensioned according to the applications requirements. The output capacitor's requirement is given in **“Functional range” on Page 8**.

## Application information

TLS835B2 is designed to be also stable with low ESR capacitors. According to the automotive requirements, ceramic capacitors with X5R or X7R dielectrics are recommended.

The output capacitor should be placed as close as possible to the voltage regulator's output pin and GND pin and on the same side of the PCB as the regulator itself.

In case of transients of input voltage or load current, the capacitance should be dimensioned in accordance and verified in the real application that the output stability requirements are fulfilled.

### 5.3 Thermal considerations

From the known input voltage, the output voltage and the load profile of the application, the total power dissipation can be calculated:

$$P_D = (V_I - V_Q)I_Q + V_i I_q \quad (5.1)$$

with

- $P_D$ : continuous power dissipation
- $V_I$ : input voltage
- $V_Q$ : output voltage
- $I_Q$ : output current
- $I_q$ : quiescent current

The maximum acceptable thermal resistance  $R_{thJA}$  is:

$$R_{th,JA} = \frac{T_{j,max} - T_a}{P_D} \quad (5.2)$$

with

- $T_{j,max}$ : maximum allowed junction temperature
- $T_a$ : ambient temperature

Based on the above calculation the proper PCB type and the necessary heat sink area can be determined with reference to the specification in **“Thermal resistance” on Page 9**.

### 5.4 Reverse polarity protection

TLS835B2 is not protected against reverse polarity faults and must be protected by external components against negative supply voltage. An external reverse polarity diode is necessary. The absolute maximum ratings of the device as specified in **“Absolute maximum ratings” on Page 7** must be maintained.

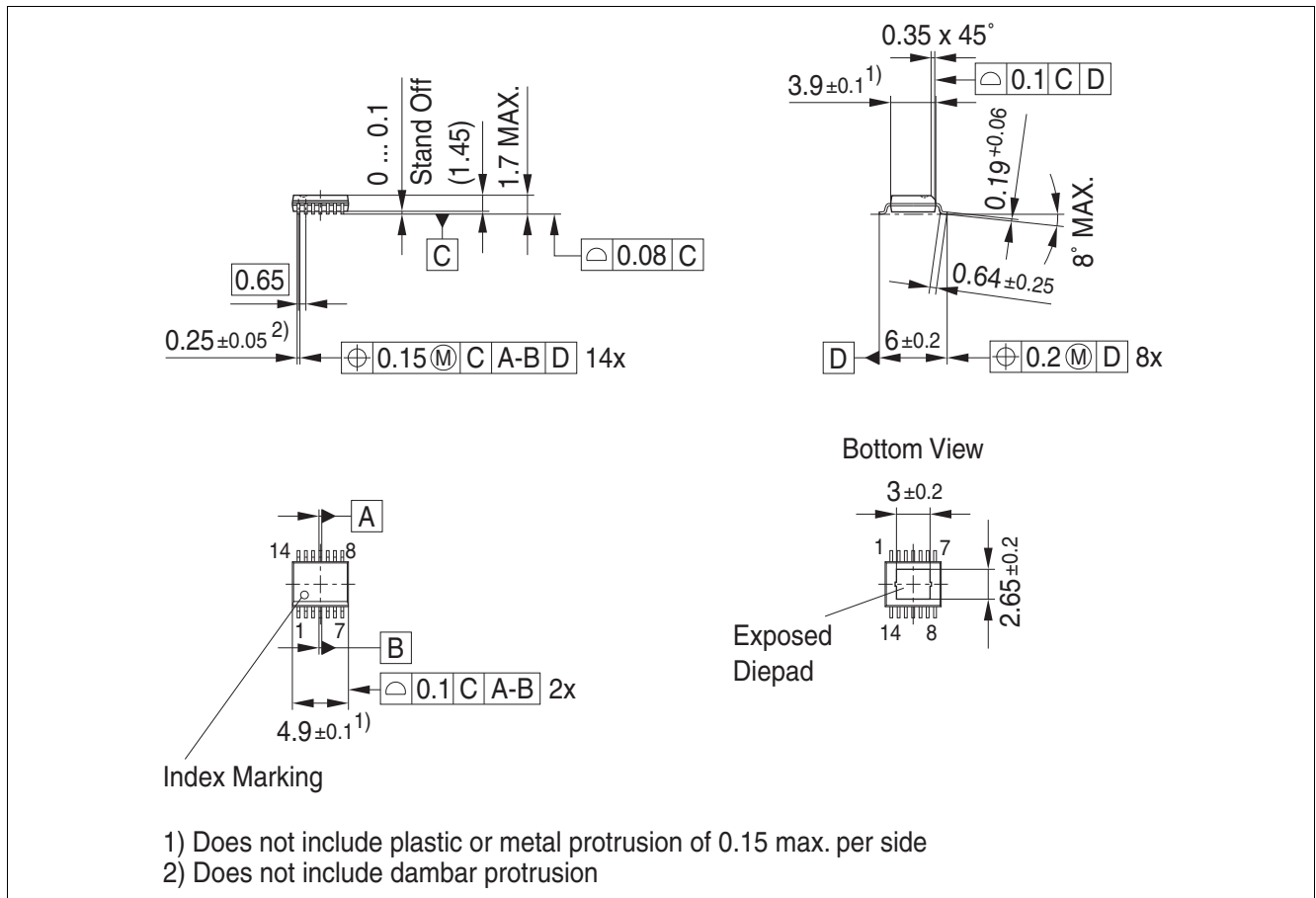
### 5.5 Further application information

For further information you may contact <http://www.infineon.com/>



**Package outlines**

**6 Package outlines**



**Figure 6 PG-SSOP-14**

**Green Product (RoHS compliant)**

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e. Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

**Revision history**

## **7 Revision history**

<b>Revision</b>	<b>Date</b>	<b>Changes</b>
1.0	2018-03-09	Initial Version

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